

	<h2 style="color: red;">FQB32N20CTM</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> FQB32N20CTM
	<b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor
	<b>Teil der Beschreibung:</b> MOSFET N-CH 200V 28A D2PAK
	<b>Datenblätter:</b>  <a href="#">FQB32N20CTM.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 1367 pcs Stock Available.
	<b>Liefern von:</b> Hong Kong
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	FQB32N20CTM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 200V 28A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	1367 pcs Stock
detaillierte Beschreibung	N-Channel 200V 28A (Tc) 3.13W (Ta), 156W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 156W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V <sub>dss</sub> )	200V
Strom - Ununterbrochener Abfluss (I <sub>d</sub> ) bei 25 ° C	28A (Tc)
R <sub>ds</sub> On (Max) @ I <sub>d</sub> , V <sub>gs</sub>	82 mOhm @ 14A, 10V
V <sub>GS</sub> (th) (Max) @ I <sub>d</sub>	4V @ 250µA
Gate Charge (Q <sub>g</sub> ) (Max) @ V <sub>gs</sub>	110nC @ 10V
Eingabekapazität (C <sub>iss</sub> ) (Max) @ V <sub>ds</sub>	2220pF @ 25V
Antriebsspannung (Max R <sub>ds</sub> On, Min R <sub>ds</sub> On)	10V
V <sub>gs</sub> (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQB32N20CTM ist neu im Original, Suche FQB32N20CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB32N20CTM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB32N20CTM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB32N20C</b> F FQB32N20C F</p>	 <p><b>FQB32N12V2TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 120V 32A D2PAK</p>	 <p><b>FQB33N10L</b> F FQB33N10L F</p>	 <p><b>FQB33N10</b> F FQB33N10 F</p>
 <p><b>FQB32N30</b> FAIRCHILD FQB32N30 FAIRCHILD</p>	 <p><b>FQB32N20</b> FSC FQB32N20 FSC</p>	 <p><b>FQB32N20CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 28A D2PAK</p>	 <p><b>FQB33N10LTM</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 33A D2PAK</p>

### heiße Teile

Mehr

FQB25N33TM_F085	FQB27N25TM	FQB27P06	D FQB27P06TM	FQB27P06TM
FQB2N50C	FQB2N60TM	D FQB2N60TM	FQB2N80TM	FQB2N80TM
FQB2NA90TM	FQB2NA90TM	FQB2P25TM	FQB2P25TM	FQB30N06
D FQB30N06L	FQB30N06LTM	FQB30N06LTM	FQB30N06TM	FQB30N06TM
FQB32N12V2	FQB32N12V2TM	FQB32N12V2TM	FQB32N20	FQB32N20C
FQB32N20CTM	FQB32N30	D FQB33N10	FQB33N10L	FQB33N10LTM
FQB33N10LTM	D FQB33N10TM	FQB33N10TM	FQB34N20	FQB34N20L
FQB34N20LTM	FQB34N20LTM	FQB34N20TM	FQB34N20TM_AM002	FQB34P10
FQB34P10TM	FQB34P10TM	FQB34P10TM_F085	D FQB3N25TM	FQB3N25TM
FQB3N30TM	FQB3N30TM	FQB3N40TM	FQB3N40TM	FQB3N60C

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